

FEATURES

- ± 5 mV ($\pm 0.2\%$) Max. Initial Tolerance (A grade)
- Wide Operating Current Range
- Low Voltage Reference 2.5V
- Max. 0.6Ω Dynamic Impedance (A grade)
- Low Temperature Coefficient

APPLICATIONS

- Power Supplies
- Instrumentation
- 8 Bit A/D, D/A Reference
- Current Loop Measurement and Control Systems
- Reference for 5V Systems

GENERAL DESCRIPTION

The AMS1009 is a precision band-gap voltage reference diode. This voltage reference features a very low dynamic impedance and good temperature coefficient, operating over a wide current range of $400\mu\text{A}$ to 10mA . On-chip trimming is used to provide tight tolerance and minimize temperature drift. A third terminal allows the reference voltage to be adjusted to $\pm 5\%$ to calibrate out system errors.

The AMS1009 is used as a precision 2.5V low voltage reference for digital voltmeters, power supplies or op amp circuitry, and the 2.5V make it easy to obtain a stable reference from 5V logic supplies.

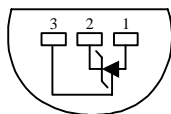
The AMS1009 is available in TO-92 and SO-8 packages operating over a 0°C to 70°C temperature range.

ORDERING INFORMATION:

TOL.	PACKAGE TYPE		OPERATING TEMPERATURE RANGE
	TO-92	8 LEAD SOIC	
$\pm 5\text{mV}$	AMS1009AN	AMS1009AS	0 to 70°C
$\pm 10\text{mV}$	AMS1009BN	AMS1009BS	0 to 70°C

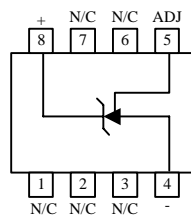
PIN CONNECTIONS

TO-92
Plastic Package (N)



Bottom View

8L SOIC
SO Package (S)



Top View

ABSOLUTE MAXIMUM RATINGS (Note 1)

Reverse Current	20mA	Soldering information (25 sec.)	265°C
Forward Current	10mA		
Operating Temperature Range	0°C to 70°C		
Storage temperature	-55°C to +150°C		

ELECTRICAL CHARACTERISTICS

Electrical Characteristics at $I_R = 1 \text{ mA}$, and $T_A = +25^\circ\text{C}$ unless otherwise specified.

Parameter	Conditions	AMS1009A			AMS1009B			Units
		Min	Typ	Max	Min	Typ	Max	
Reverse Breakdown Voltage		2.495	2.500	2.505	2.490	2.500	2.510	V
Reverse Dynamic Impedance			0.2 0.4	0.6 1.4		0.2 0.4	1.0 1.4	Ω
Reverse Breakdown Voltage Change with current	$400\mu\text{A} \leq I_R \leq 10\text{mA}$		2.6 3	10 12		2.6 3	10 12	mV
Temperature Stability	$T_{\text{MIN}} \leq T_A \leq T_{\text{MAX}}$		1.8	4		1.8	4	mV
Average Temperature Coeff.	$0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$		15	25		15	25	ppm/ $^\circ\text{C}$
Long Term Stability (Note 4)	$T_A = 25^\circ\text{C} \pm 1^\circ\text{C}$ $T = 1000 \text{ Hr}$		20			20		ppm

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.

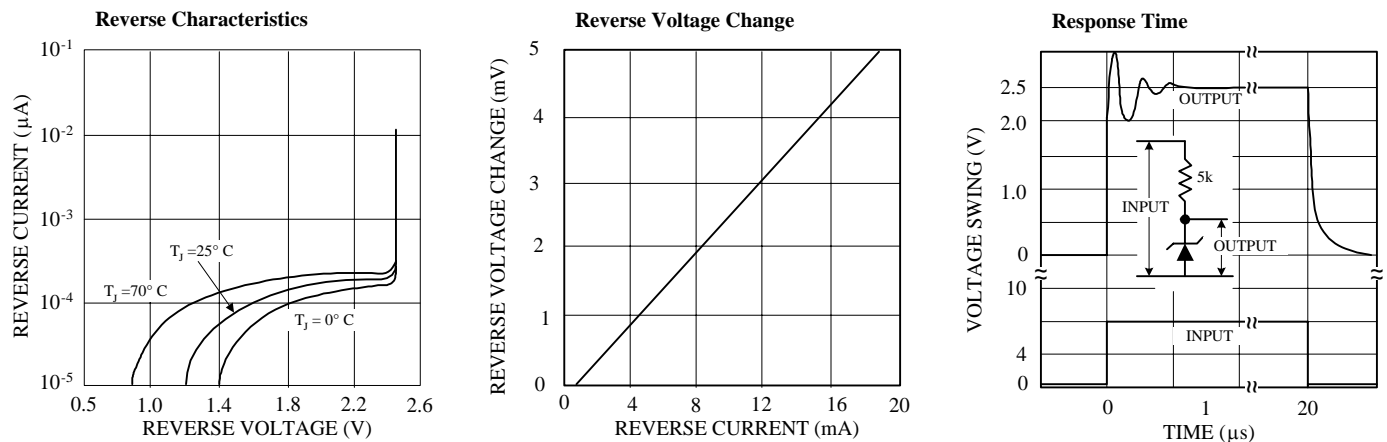
Note 2: For elevated temperature operation, T_j max is $+125^\circ\text{C}$

Thermal Resistance	TO-92	SO-8
ϕ_{JA} (junction to ambient)	170°C/W (0.125" leads)	165°C/W

Note 3: Parameters identified with **boldface type** apply at temperature extremes. All other numbers apply at $T_A = T_j = 25^\circ\text{C}$.

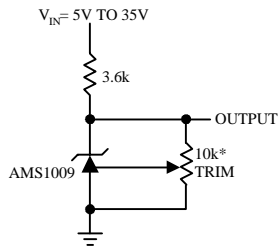
Note 4: The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures between the operating T_{MAX} and T_{MIN} , divided by $T_{\text{MAX}} - T_{\text{MIN}}$. The measured temperatures are 0°C , 25°C and 70°C .

TYPICAL PERFORMANCE CHARACTERISTICS

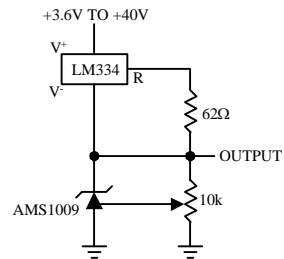


TYPICAL APPLICATIONS

2.5V Reference

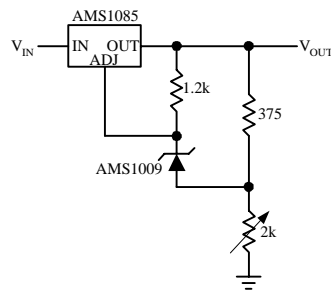


Wide Supply Range, Adjustable Reference



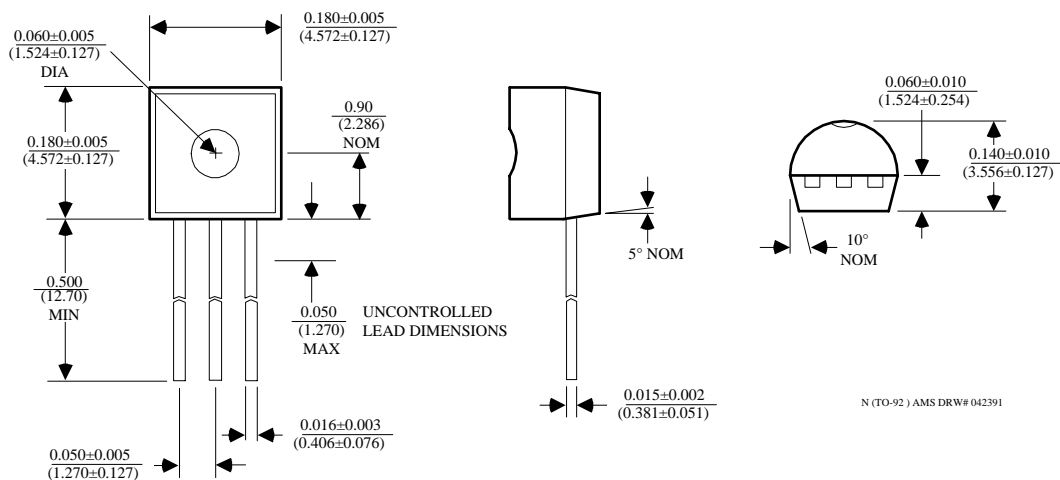
*Does not affect Temperature Coefficient

Low Temperature Coefficient Power Regulator



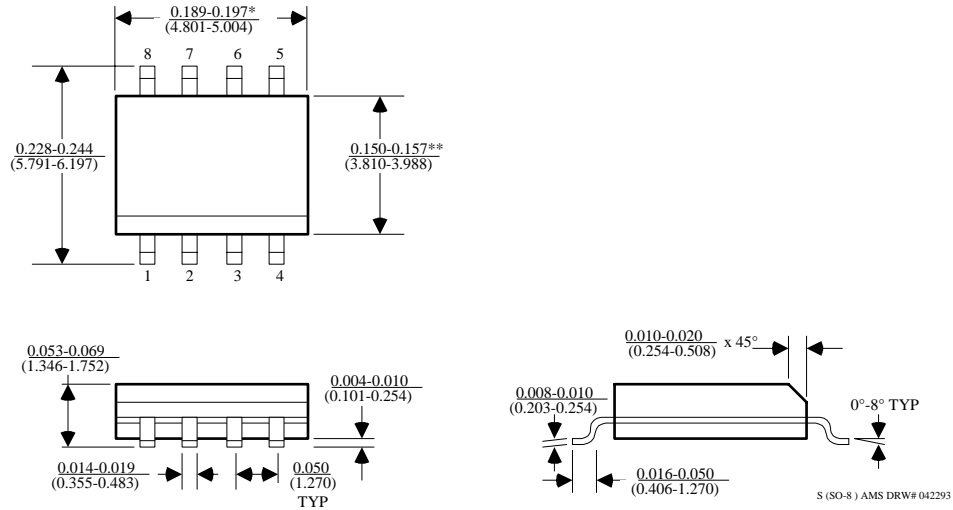
PACKAGE DIMENSIONS inches (millimeters) unless otherwise noted.

3 LEAD TO-92 PLASTIC PACKAGE (N)



PACKAGE DIMENSIONS inches (millimeters) unless otherwise noted (Continued).

8 LEAD SOIC PLASTIC PACKAGE (S)



*DIMENSION DOES NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE

**DIMENSION DOES NOT INCLUDE INTERLEAD FLASH. INTERLEAD FLASH SHALL NOT EXCEED 0.010" (0.254mm) PER SIDE